



SYNSEMI SEMICONDUCTOR

SK12 thru SK16

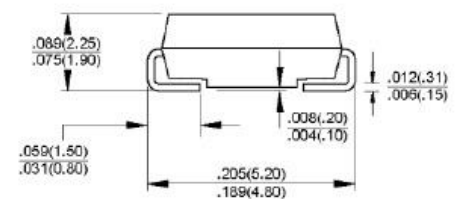
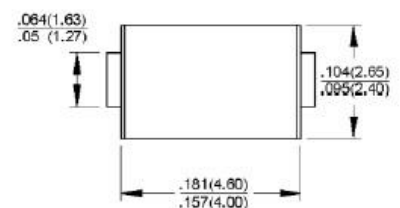
1.0 Amp. Surface Mount Schottky Barrier Rectifiers
Voltage Range 20 to 60 Volts Forward Current 1.0 Ampere

Features

- ◆ For surface mounted applications
- ◆ Metal-Semiconductor junction with guardring
- ◆ Epitaxial construction
- ◆ Very low forward voltage drop
- ◆ High current capability
- ◆ Plastic material has UL flammability classification 94V-0
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



DO-214AC (SMA)



Dimensions in inches and (millimeters)

Mechanical Data

- ◆ Case : JEDEC DO-214AC(SMA) molded plastic
- ◆ Polarity : Indicated by cathode band
- ◆ Weight : 0.002 ounce, 0.064 gram

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	SK12	SK13	SK14	SK15	SK16	Units
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	Volts
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	Volts
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	Volts
Maximum average forward rectified current @ $T_L=100^{\circ}\text{C}$	$I_{(AV)}$	1.0					Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30.0					Amps
Maximum forward voltage at 1.0A DC	V_F	0.50			0.70		Volts
Maximum DC reverse current @ $T_J=25^{\circ}\text{C}$ at rated DC blocking voltage @ $T_J=100^{\circ}\text{C}$	I_R	0.5 10.0					mA
Typical junction capacitance (Note 1)	C_J	110					pF
Typical thermal resistance (Note 2)	$R_{\theta AL}$	20					$^{\circ}\text{C/W}$
Operating temperature range	T_J	-55 to +125					$^{\circ}\text{C}$
Storage temperature range	T_{STG}	-55 to +150					$^{\circ}\text{C}$

Notes: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2. Thermal Resistance Junction to Lead.

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RATINGS AND CHARACTERISTIC CURVES

